# onsemi

# General Purpose Transistors

# **PNP Silicon**

# **MMBT3906TT1**

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications.

### Features

- NSVM Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ )

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-40	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	-200	mAdc

#### THERMAL CHARACTERISTICS

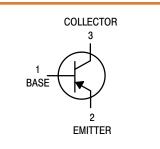
Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) @T <sub>A</sub> = 25°C Derated above 25°C	P <sub>D</sub>	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) @T <sub>A</sub> = 25°C Derated above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\thetaJA}$	400	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

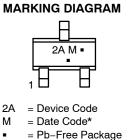
1. FR-4 @ Minimum Pad

2. FR-4 @  $1.0 \times 1.0$  Inch Pad

# GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT







(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

## ORDERING INFORMATION

Device	Package	Shipping <sub>†</sub>
MMBT3906TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel
NSVMMBT3906TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (Note 3) ( $I_C = -1.0 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	-40	-	Vdc
Collector – Base Breakdown Voltage $(I_C = -10 \ \mu Adc, I_E = 0)$	V <sub>(BR)CBO</sub>	-40	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_C = 0)$	V <sub>(BR)EBO</sub>	-5.0	_	Vdc
Base Cutoff Current (V <sub>CE</sub> = -30 Vdc, V <sub>EB</sub> = -3.0 Vdc)	I <sub>BL</sub>	_	-50	nAdc
Collector Cutoff Current (V <sub>CE</sub> = -30 Vdc, V <sub>EB</sub> = -3.0 Vdc)	I <sub>CEX</sub>	_	-50	nAdc
ON CHARACTERISTICS (Note 3)				
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = -0.1 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -1.0 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -10 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -50 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -100 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -100 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \end{array} $	h <sub>FE</sub>	60 80 100 60 30	- - 300 - -	_
Collector – Emitter Saturation Voltage $(I_{C} = -10 \text{ mAdc}, I_{B} = -1.0 \text{ mAdc})$ $(I_{C} = -50 \text{ mAdc}, I_{B} = -5.0 \text{ mAdc})$	V <sub>CE(sat)</sub>		-0.25 -0.4	Vdc
Base – Emitter Saturation Voltage $(I_{C} = -10 \text{ mAdc}, I_{B} = -1.0 \text{ mAdc})$ $(I_{C} = -50 \text{ mAdc}, I_{B} = -5.0 \text{ mAdc})$	V <sub>BE(sat)</sub>	-0.65 -	-0.85 -0.95	Vdc

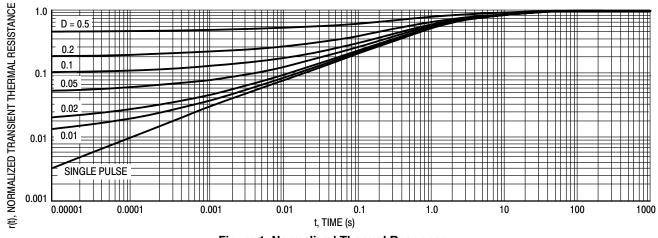
#### SMALL-SIGNAL CHARACTERISTICS

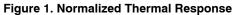
Current – Gain – Bandwidth Product ( $I_C = -10 \text{ mAdc}, V_{CE} = -20 \text{ Vdc}, f = 100 \text{ MHz}$ )	f <sub>T</sub>	250	_	MHz
Output Capacitance (V <sub>CB</sub> = -5.0 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	_	4.5	pF
Input Capacitance1 (V <sub>EB</sub> = -0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ibo</sub>	_	10.0	pF
Input Impedance (V <sub>CE</sub> = -10 Vdc, I <sub>C</sub> = -1.0 mAdc, f = 1.0 kHz)	h <sub>ie</sub>	2.0	12	kΩ
Voltage Feedback Ratio (V <sub>CE</sub> = -10 Vdc, I <sub>C</sub> = -1.0 mAdc, f = 1.0 kHz)	h <sub>re</sub>	0.1	10	X 10 <sup>-4</sup>
Small – Signal Current Gain (V <sub>CE</sub> = -10 Vdc, I <sub>C</sub> = -1.0 mAdc, f = 1.0 kHz)	h <sub>fe</sub>	100	400	-
Output Admittance (V <sub>CE</sub> = -10 Vdc, I <sub>C</sub> = -1.0 mAdc, f = 1.0 kHz)	h <sub>oe</sub>	3.0	60	μmhos
Noise Figure (V <sub>CE</sub> = –5.0 Vdc, I <sub>C</sub> = –100 $\mu$ Adc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz)	NF	-	4.0	dB

#### SWITCHING CHARACTERISTICS

Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, \text{ V}_{BE} = 0.5 \text{ Vdc})$	t <sub>d</sub>	-	35	
Rise Time	$(I_{C} = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$	t <sub>r</sub>	-	35	ns
Storage Time	$(V_{CC} = -3.0 \text{ Vdc}, I_C = -10 \text{ mAdc})$	t <sub>s</sub>	-	225	ns
Fall Time	(I <sub>B1</sub> = I <sub>B2</sub> = -1.0 mAdc)	t <sub>f</sub>	-	75	115

3. Pulse Test: Pulse Width  $\leq$  300  $\mu s,$  Duty Cycle  $\leq$  2.0%.





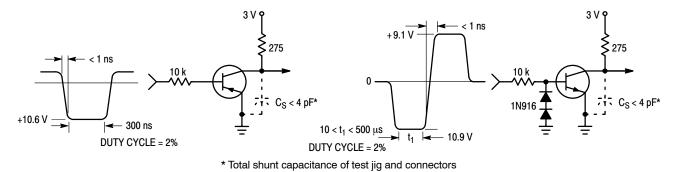
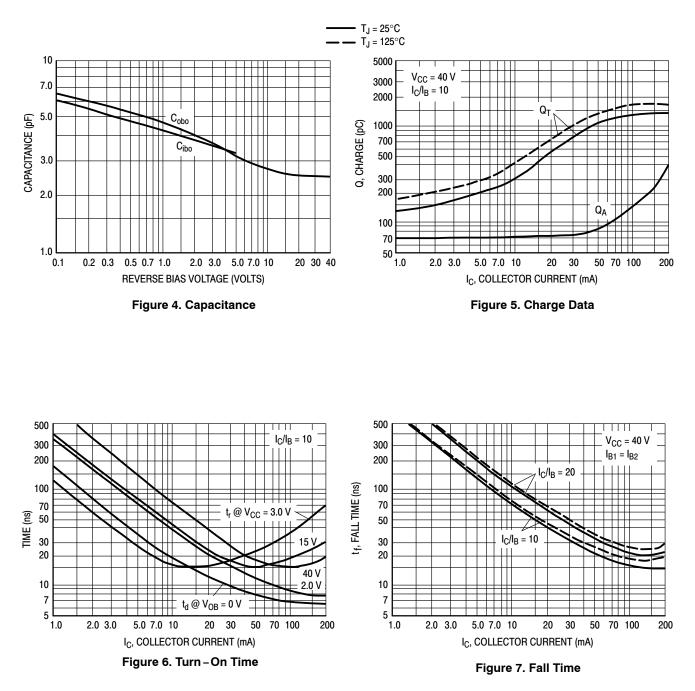


Figure 2. Delay and Rise Time Equivalent Test Circuit Figure 3. Storage and Fall Time Equivalent Test Circuit

## **TYPICAL TRANSIENT CHARACTERISTICS**



### **TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS**

(V<sub>CE</sub> = -5.0 Vdc, T<sub>A</sub> =  $25^{\circ}$ C, Bandwidth = 1.0 Hz)

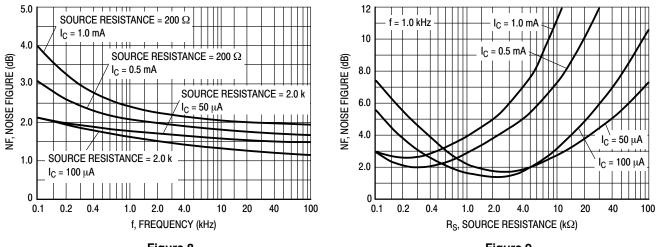
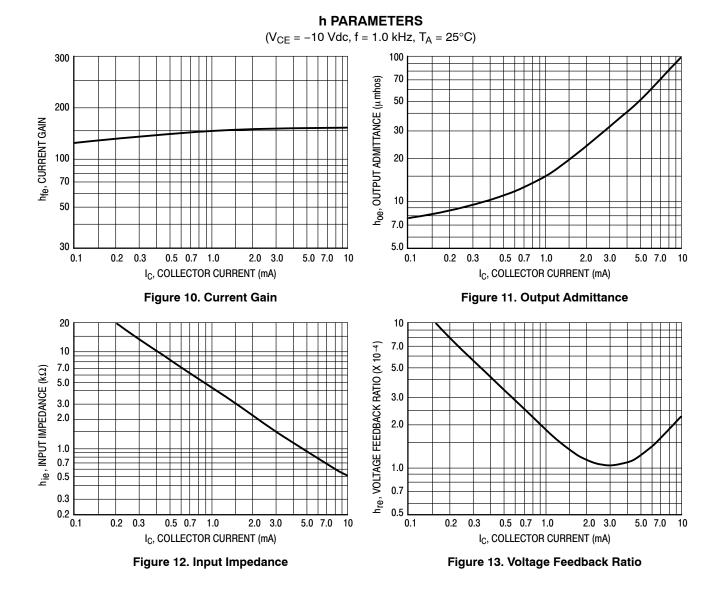
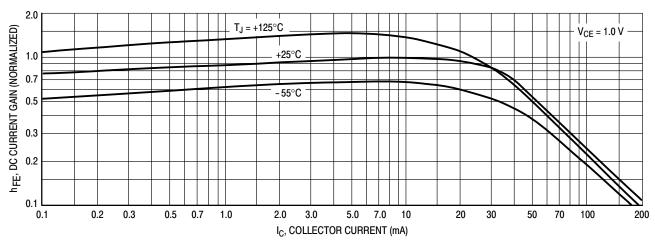




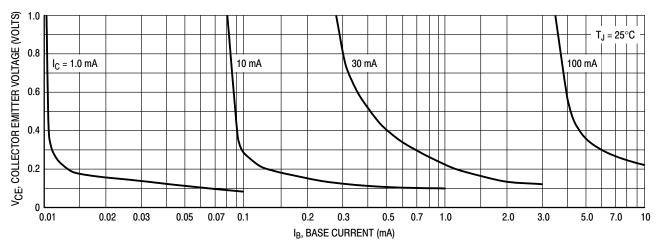
Figure 9.



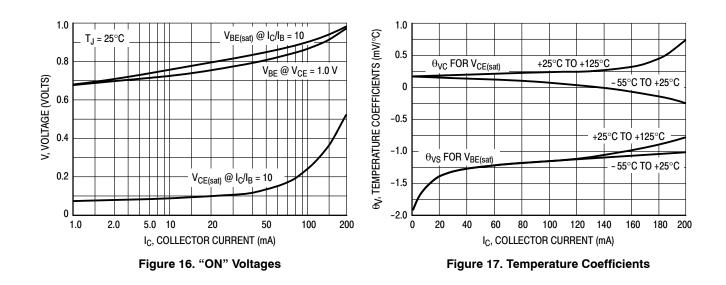




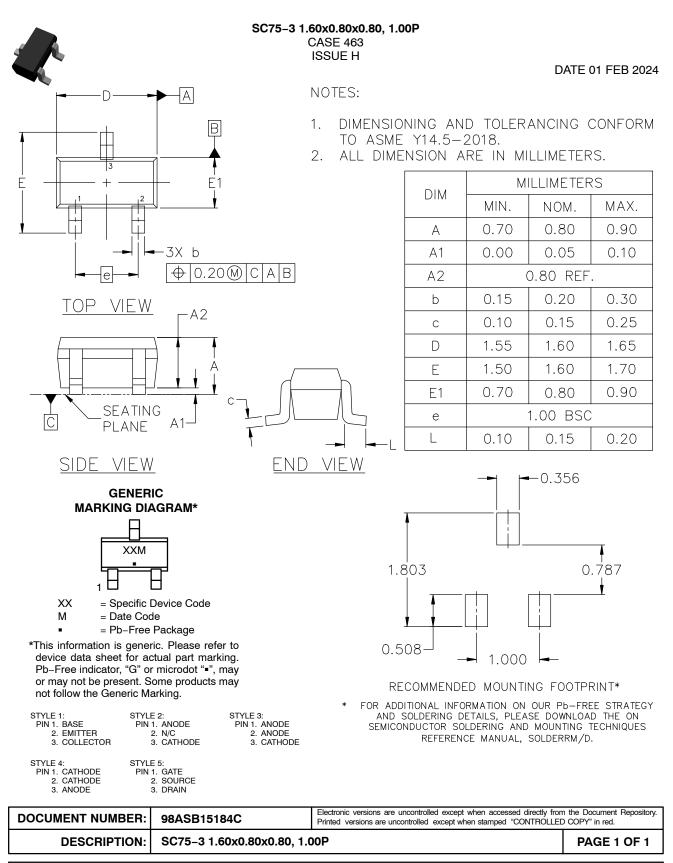












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